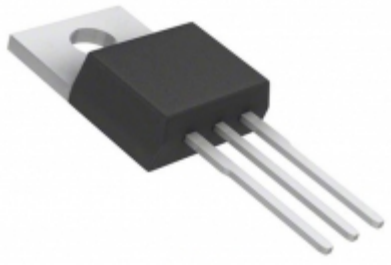


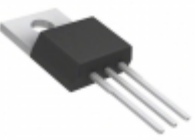
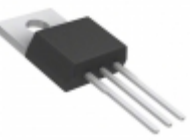



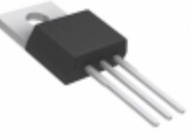
	<h2 style="color: red;">FQP7N20L</h2> <p>Hersteller-Teilenummer: FQP7N20L</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 6.5A TO-220</p> <p>Datenblätter: 1.FQP7N20L.pdf 2.FQP7N20L.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 33552 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP7N20L
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 6.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	33552 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	63W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	6.5A (Tc)
Rds On (Max) @ Id, Vgs	750 mOhm @ 3.25A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	500pF @ 25V
Verpackung	Tube

FQP7N20L ist neu im Original, Suche FQP7N20L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP7N20L Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP7N20L: Info@Y-IC.com

Sie können auch interessiert sein:

 FQP7N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 7.3A TO-220	 FQP7N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 7.3A TO-220	 FQP7N60 Fairchild/ON Semiconductor MOSFET N-CH 600V 7.4A TO-220	 FQP7N40 AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 7A TO-220
 FQP7N60 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.4A TO-220	 FQP7N20 Fairchild/ON Semiconductor MOSFET N-CH 200V 6.6A TO-220	 FQP7N40 Fairchild/ON Semiconductor MOSFET N-CH 400V 7A TO-220	 FQP7N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 7.3A TO-220

heiße Teile

Mehr

⊗ FQP630TSTU	↔ FQP65N06	⇒ FQP65N06	D FQP6N40C	↔ FQP6N40C
⊣ FQP6N40CF	⊗ FQP6N40CF	D FQP6N50C	⇒ FQP6N50C	↔ FQP6N60C
⊗ FQP6N60C	⊣ FQP6N80C	⊗ FQP6N80C	↔ FQP6N90C	↔ FQP6N90C
D FQP70N03L	⊗ FQP70N06	⊣ FQP70N06C	⊗ FQP70N08	↔ FQP70N08
⇒ FQP70N10	↔ FQP70N10	⊗ FQP7N10L	⊣ FQP7N10L	↔ FQP7N20L
↔ FQP7N60C	⇒ FQP7N65C	D FQP7N65C	⊗ FQP7N80C	⊣ FQP7N80C
⊗ FQP85N06	D FQP85N06	⇒ FQP8N50C	↔ FQP8N60C	↔ FQP8N60C
⊣ FQP8N65C	⊗ FQP8N80C	↔ FQP8N80C	⇒ FQP8N90C	↔ FQP8N90C
⊗ FQP90N08	⊣ FQP90N08	⊗ FQP90N10V2	D FQP90N10V2	↔ FQP9N08L
↔ FQP9N08L	⊗ FQP9N25C	⊣ FQP9N25C	⊗ FQP9N50C	↔ FQP9N50C

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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